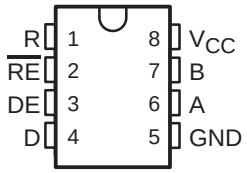
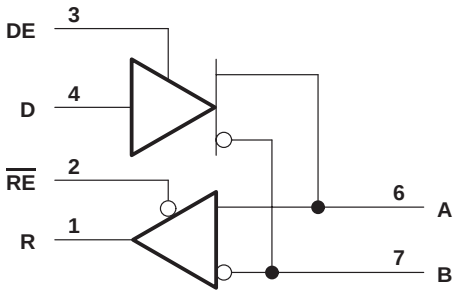
- **Low-Voltage Differential Driver and Receiver for Half-Duplex Operation**
- **Designed for Signaling Rates of 400 Mbit/s**
- **ESD Protection Exceeds 15 kV on Bus Pins**
- **Operates From a Single 3.3-V Supply**
- **Low-Voltage Differential Signaling With Typical Output Voltages of 350 mV and a 50-Ω Load**
- **Valid Output With as Little as 50 mV Input Voltage Difference**
- **Propagation Delay Times**
  - **Driver: 1.7 ns Typ**
  - **Receiver: 3.7 ns Typ**
- **Power Dissipation at 200 MHz**
  - **Driver: 50 mW Typical**
  - **Receiver: 60 mW Typical**
- **LVTTL Levels Are 5-V Tolerant**
- **Bus Pins Are High Impedance When Disabled or With V_{CC} Less Than 1.5 V**
- **Open-Circuit Fail-Safe Receiver**
- **Surface-Mount Packaging**
  - **D Package (SOIC)**
  - **DGK Package (MSOP)**

SN65LVDM176D (Marked as **DM176** or **LVM176)**
SN65LVDM176DGK (Marked as **M76**)
(TOP VIEW)



logic diagram (positive logic)



description

The SN65LVDM176 is a differential line driver and receiver configured as a transceiver that uses low-voltage differential signaling (LVDS) to achieve signaling rates as high as 400 Mbit/s. These circuits are similar to TIA/EIA-644 standard compliant devices (SN65LVDS) counterparts except that the output current of the drivers is doubled. This modification provides a minimum differential output voltage magnitude of 247 mV into a 50-Ω load and allows double-terminated lines and half-duplex operation. The receivers detect a voltage difference of less than 50 mV with up to 1 V of ground potential difference between a transmitter and receiver.

The intended application of this device and signaling technique is for half-duplex or multiplex baseband data transmission over controlled impedance media of approximately 100-Ω characteristic impedance. The transmission media may be printed-circuit board traces, backplanes, or cables. (Note: The ultimate rate and distance of data transfer is dependent upon the attenuation characteristics of the media, the noise coupling to the environment, and other application specific characteristics).

The SN65LVDM176 is characterized for operation from –40°C to 85°C.

AVAILABLE OPTIONS

T_A	PACKAGE	
	SMALL OUTLINE (D)†	MSOP (DGK)†
–40°C to 85°C	SN65LVDM176D	SN65LVDM176DGK

† The D package is available taped and reeled. Add the suffix R to the device type (e.g., SN65LVDM176DR).

Function Tables

DRIVER

INPUT D	ENABLE DE	OUTPUTS	
		A	B
L	H	L	H
H	H	H	L
Open	H	L	H
X	L	Z	Z

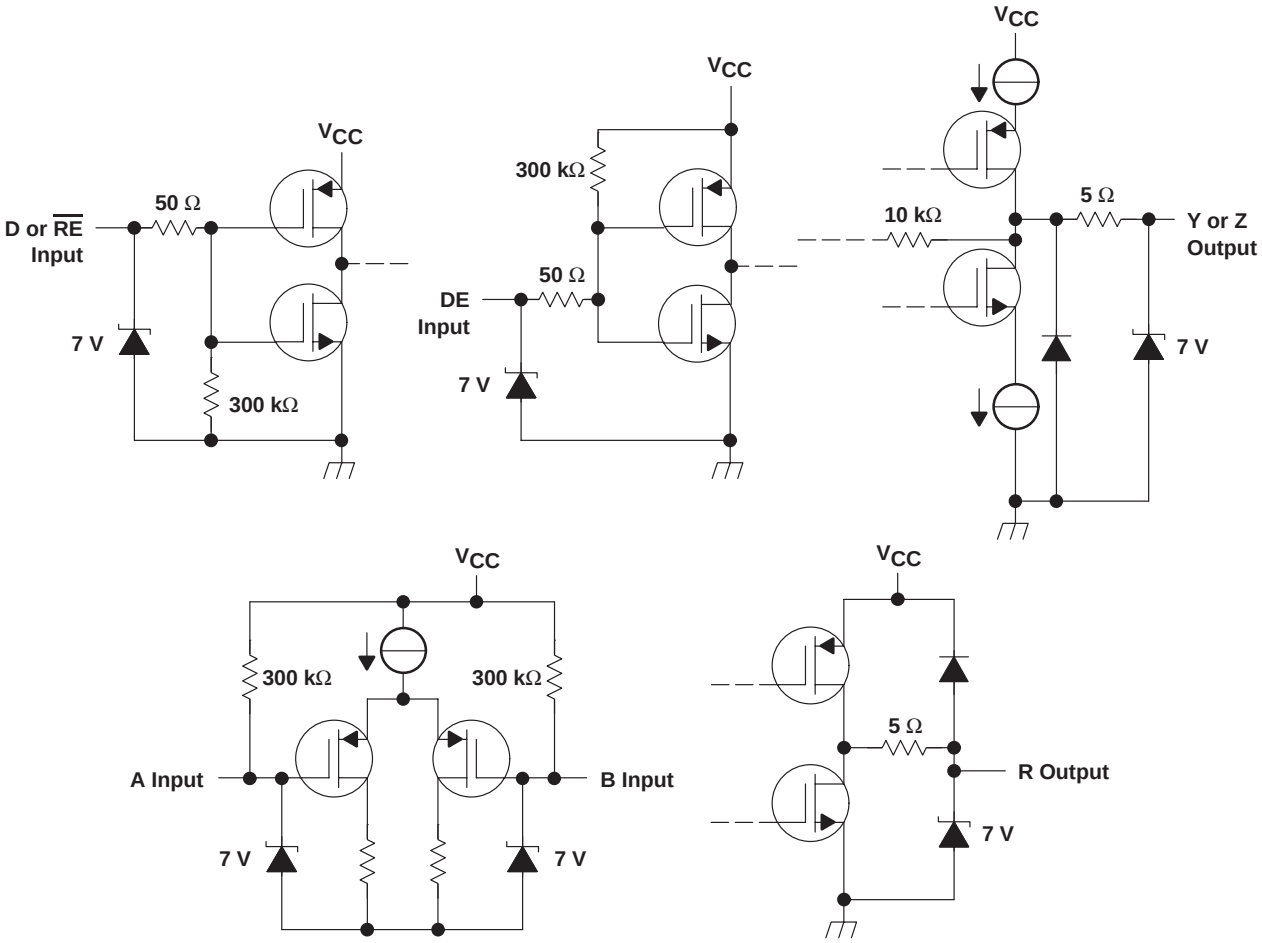
H = high level, L = low level, X = irrelevant,
Z = high impedance

RECEIVER

DIFFERENTIAL INPUTS $V_{ID} = V_A - V_B$	ENABLE $\overline{RE}$	OUTPUT R
$V_{ID} \geq 50$ mV	L	H
–50 mV < V_{ID} < 50 mV	L	?
$V_{ID} \leq$ –50 mV	L	L
Open	L	H
X	H	Z

H = high level, L = low level, X = irrelevant,
Z = high impedance

equivalent input and output schematic diagrams



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC} (see Note 1) . . . . . –0.5 V to 4 V
Input voltage range, D, R, DE, $\overline{RE}$ . . . . . –0.5 V to 6 V
A or B . . . . . –0.5 V to 4 V
Electrostatic discharge; A, B , and GND (see Note 2) . . . . . CLass 3, A:15 kV, B:600 V
All terminals . . . . . Class 3, A:7 kV, B:500 V
Continuous total power dissipation . . . . . See Dissipation Rating Table
Operating free-air temperature range, T_A . . . . . –40°C to 85°C
Storage temperature range, T_{stg} . . . . . –65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds . . . . . 260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential I/O bus voltage, are with respect to network ground terminal.
2. Tested in accordance with MIL-STD-883C Method 3015.7.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$	$T_A = 85°C$ POWER RATING
D	725 mW	5.8 mW/°C	377 mW
DGK	424 mW	3.4 mW/°C	220 mW

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}	3	3.3	3.6	V
High-level input voltage, V_{IH}	2			V
Low-level input voltage, V_{IL}			0.8	V
Magnitude of differential input voltage, $\lvert V_{ID} \rvert$	0.1		0.6	V
Common–mode input voltage, V_{IC} (see Figure 1)	$\frac{\lvert V_{ID} \rvert}{2}$		$2.4 - \frac{\lvert V_{ID} \rvert}{2}$	V
			$V_{CC}–0.8$	
Operating free–air temperature, T_A	–40		85	°C

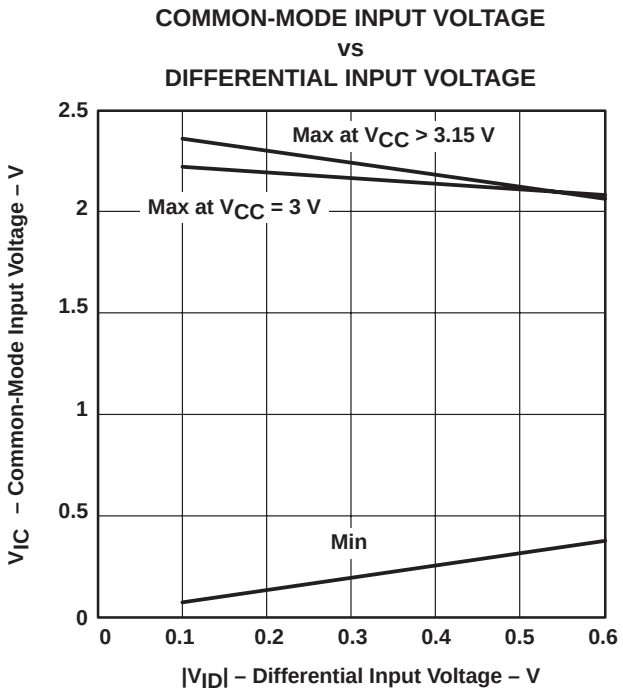


Figure 1

device electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
I_{CC}	Supply current	Driver and receiver enabled, no receiver load, driver R_L = 50 Ω		10	15	mA
		Driver enabled, receiver disabled, R_L = 50 Ω		9	15	
		Driver disabled, receiver enabled, no load		1.8	5	
		Disabled		0.5	2	

† All typical values are at 25°C and with a 3.3-V supply.

driver electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
$\|V_{OD}\|$	Differential output voltage magnitude		R_L = 50Ω, See Figure 2 and Figure 3	247	340	454	mV
$\Delta\|V_{OD}\|$	Change in differential output voltage magnitude between logic states			–50		50	
$V_{OC(SS)}$	Steady-state common-mode output voltage		See Figure 4	1.125		1.375	V
$\Delta V_{OC(SS)}$	Change in steady-state common-mode output voltage between logic states			–50		50	mV
$V_{OC(PP)}$	Peak-to-peak common-mode output voltage				50	150	mV
I_{IH}	High-level input current†	DE	V_{IH} = 5 V		0.5	10	μA
		D			2	20	
I_{IL}	Low-level input current†	DE	V_{IL} = 0.8 V		–0.5	–10	μA
		D			2	10	
I_{OS}	Short-circuit output current†		V_{OA} or V_{OB} = 0 V			–10	mA
			V_{OD} = 0 V			–10	
C_I	Input capacitance				3		pF

† The non-algebraic convention, where the more positive (least negative) limit is designated maximum, is used in this data sheet for this parameter.

receiver electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
V_{IT+}	Positive-going differential input voltage threshold	See Figure 6			50	mV
$V_{IT–}$	Negative-going differential input voltage threshold		–50			
V_{OH}	High-level output voltage	I_{OH} = –8 mA	2.4			V
V_{OL}	Low-level output voltage	I_{OL} = 8 mA			0.4	V
I_I	Input current (A or B inputs)‡	V_I = 0 V	–2		–20	μA
		V_I = 2.4 V	–1.2			
$I_{I(OFF)}$	Power-off input current (A or B inputs)	V_{CC} = 0 V or 1.8 V			20	μA
I_{IH}	High-level input current (enables)	V_{IH} = 5 V			10	μA
I_{IL}	Low-level input current (enables)	V_{IL} = 0.8 V			10	μA
I_{OZ}	High-impedance output current‡	V_O = 0 V or 5 V			±1	μA

† All typical values are at 25°C and with a 3.3-V supply.
‡ The non-algebraic convention, where the more positive (least negative) limit is designated maximum, is used in this data sheet for this parameter.

driver switching characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output	R_L = 50Ω, C_L = 10 pF, See Figure 3	0.5	1.7	2.7	ns
t_{PHL}	Propagation delay time, high-to-low-level output		0.5	1.7	2.7	
$t_{sk(p)}$	Pulse skew ($\|t_{pHL} - t_{pLH}\|$)			0.2		ns
t_r	Differential output signal rise time			0.6	1	ns
t_f	Differential output signal fall time			0.6	1	
$t_{sk(pp)}$‡	Part-to-part skew				1	ns
t_{PZH}	Propagation delay time, high-impedance-to-high-level output	See Figure 5		8	12	ns
t_{PZL}	Propagation delay time, high-impedance-to-low-level output			7	10	
t_{PHZ}	Propagation delay time, high-level-to-high-impedance output			3	10	
t_{PLZ}	Propagation delay time, low-level-to-high-impedance output			4	10	

† All typical values are at 25°C and with a 3.3 V supply.
‡ $t_{sk(pp)}$ is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

receiver switching characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output	C_L = 10 pF, See Figure 7	2.3	3.7	4.5	ns
t_{PHL}	Propagation delay time, high-to-low-level output		2.3	3.7	4.5	
$t_{sk(p)}$	Pulse skew ($\|t_{pHL} - t_{pLH}\|$)			0.4		
t_r	Output signal rise time			0.8	1.5	ns
t_f	Output signal fall time			0.8	1.5	
$t_{sk(pp)}$‡	Part–to–part skew				1	ns
t_{PZH}	Propagation delay time, high-level-to-high-impedance output	See Figure 8		3	10	ns
t_{PZL}	Propagation delay time, low-level-to-low-impedance output			3	10	
t_{PHZ}	Propagation delay time, high-impedance-to-high-level output			4	10	
t_{PLZ}	Propagation delay time, low-impedance-to-high-level output			6	10	

† All typical values are at 25°C and with a 3.3-V supply.
‡ $t_{sk(pp)}$ is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

PARAMETER MEASUREMENT INFORMATION

driver

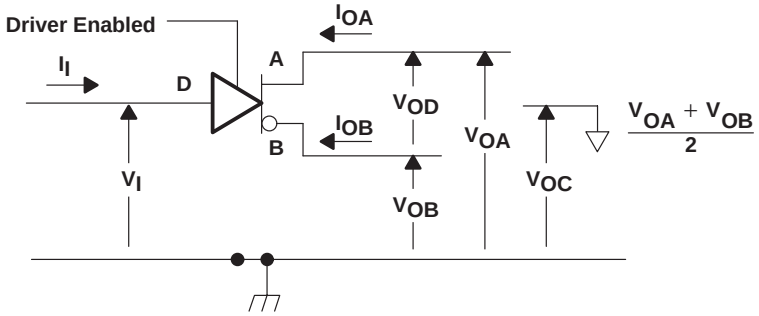
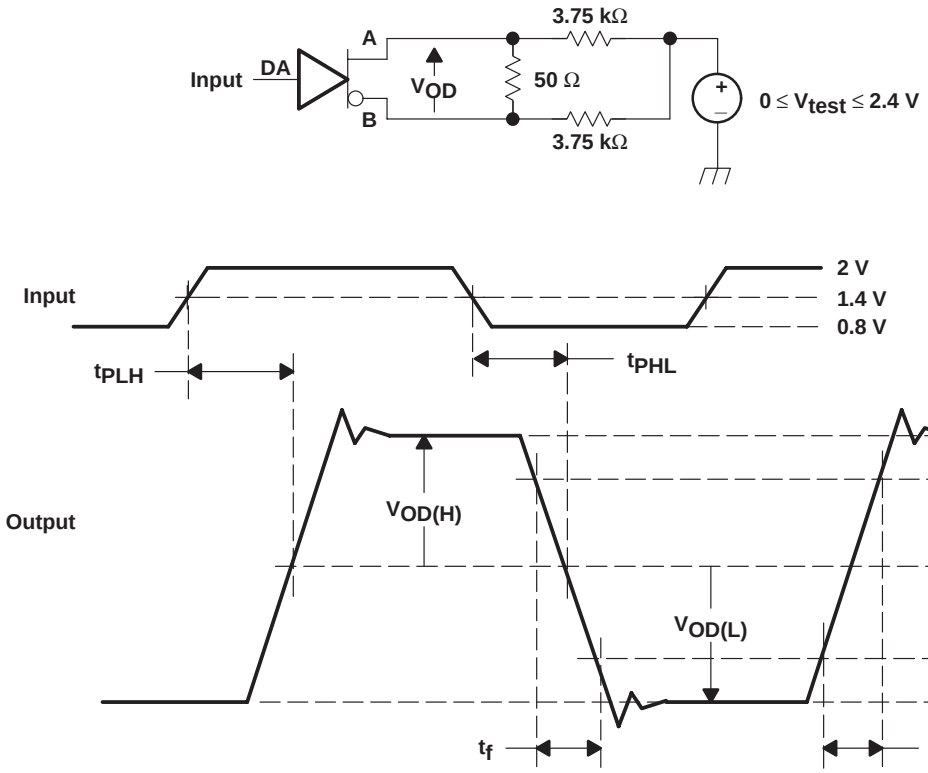


Figure 2. Driver Voltage and Current Definitions

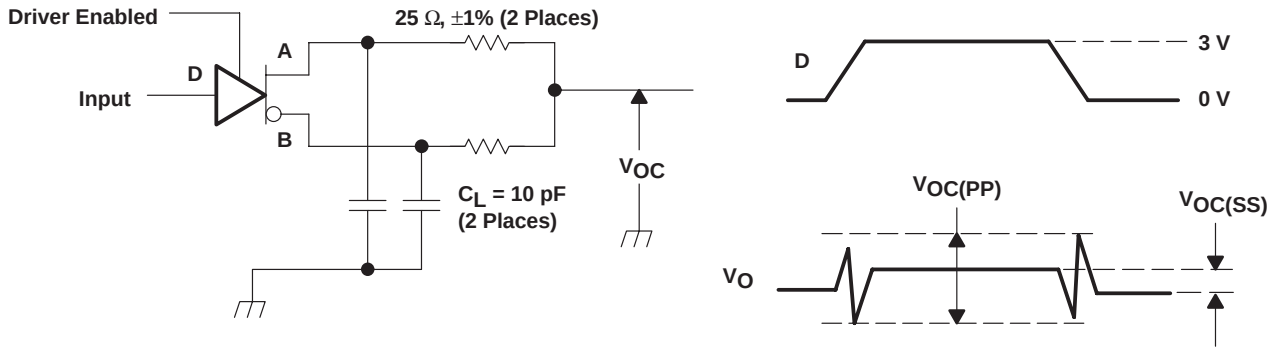


NOTE A: All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \le 1$ ns, pulse repetition rate (PRR) = 50 Mpps, pulse width = 10 ± 0.2 ns . C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

Figure 3. Test Circuit, Timing, and Voltage Definitions for the Differential Output Signal

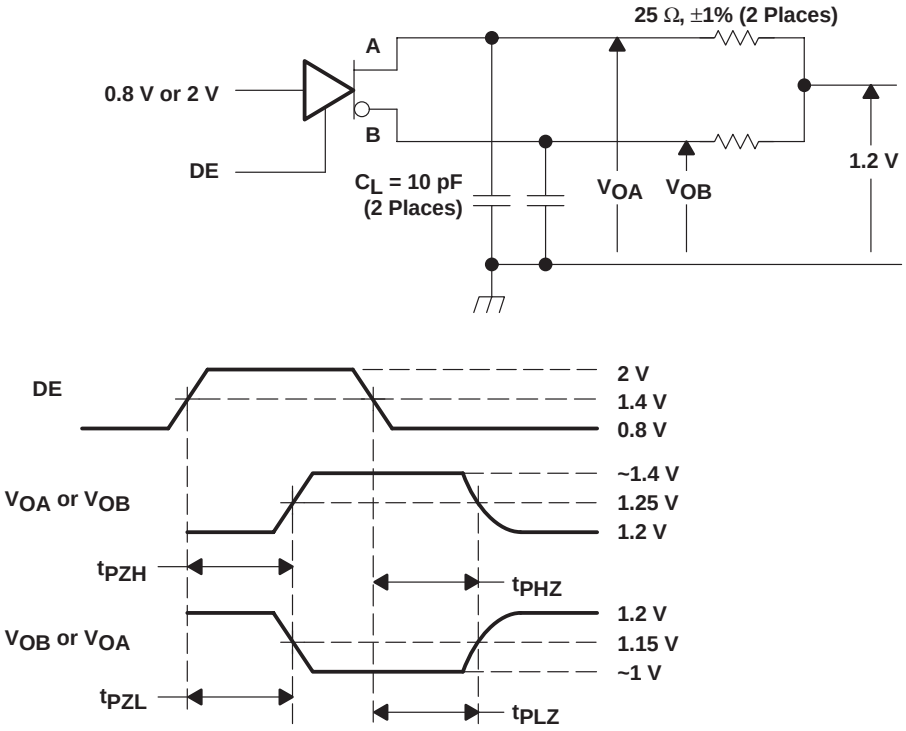
PARAMETER MEASUREMENT INFORMATION

driver (continued)



NOTE A: All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1$ ns, pulse repetition rate (PRR) = 0.5 Mpps, pulse width = 500 ± 10 ns . C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T. The measurement of $V_{OC(PP)}$ is made on test equipment with a –3 dB bandwidth of at least 300 MHz.

Figure 4. Test Circuit and Definitions for the Driver Common-Mode Output Voltage



NOTE A: All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1$ ns, pulse repetition rate (PRR) = 0.5 Mpps, pulse width = 500 ± 10 ns . C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

Figure 5. Enable and Disable Time Circuit and Definitions

PARAMETER MEASUREMENT INFORMATION

receiver

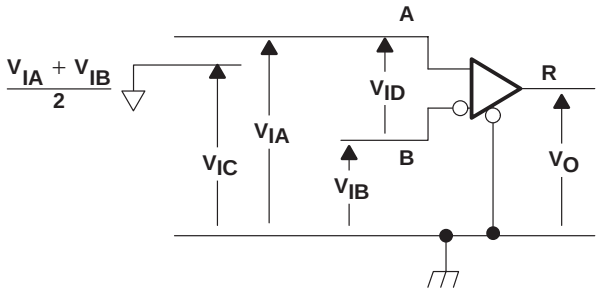


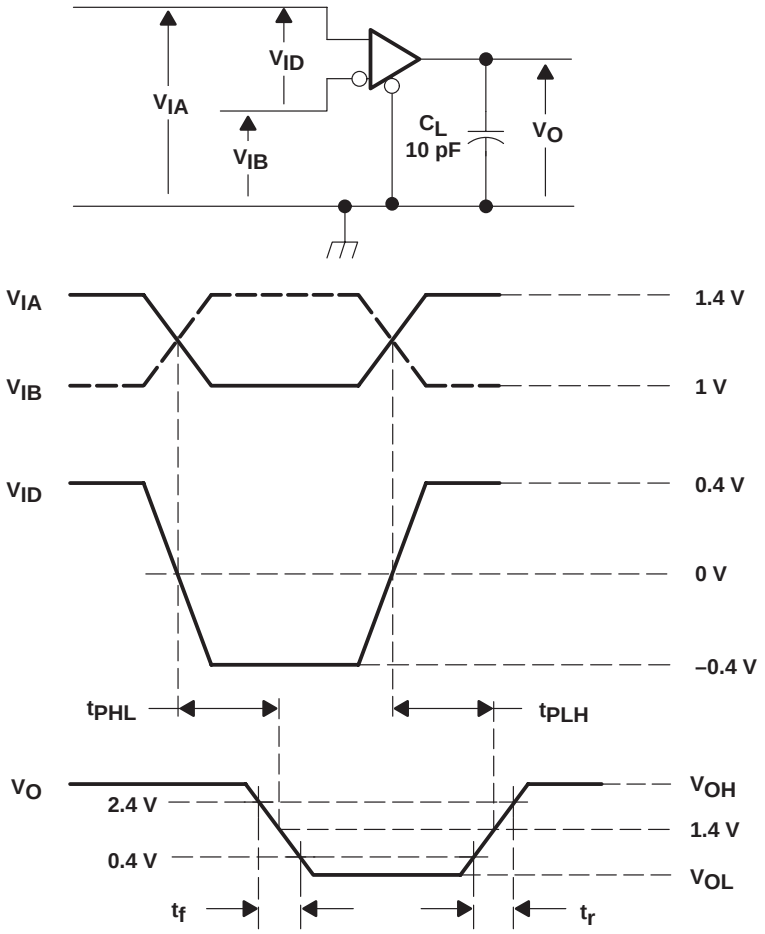
Figure 6. Receiver Voltage Definitions

Table 1. Receiver Minimum and Maximum Input Threshold Test Voltages

APPLIED VOLTAGES (V)		RESULTING DIFFERENTIAL INPUT VOLTAGE (mV)	RESULTING COMMON-MODE INPUT VOLTAGE (V)
V_{IA}	V_{IB}	V_{ID}	V_{IC}
1.225	1.175	50	1.2
1.175	1.225	–50	1.2
2.41	2.36	50	2.385
2.36	2.41	–50	2.385
0.05	0	50	0.025
0	0.05	–50	0.025
1.5	0.9	600	1.2
0.9	1.5	–600	1.2
2.4	1.8	600	2.1
1.8	2.4	–600	2.1
0.6	0	600	0.3
0	0.6	–600	0.3

PARAMETER MEASUREMENT INFORMATION

receiver (continued)

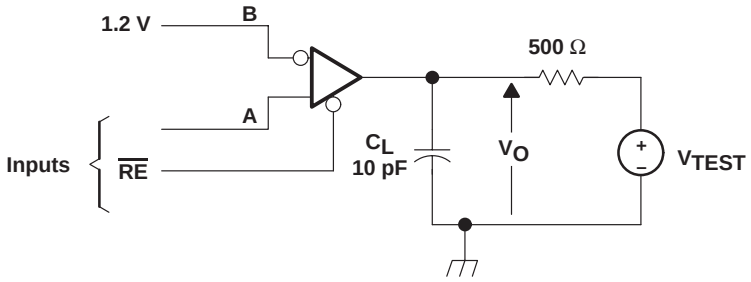


NOTE A: All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1$ ns, pulse repetition rate (PRR) = 50 Mpps, pulse width = 10 ± 0.2 ns. C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

Figure 7. Timing Test Circuit and Waveforms

PARAMETER MEASUREMENT INFORMATION

receiver (continued)



NOTE A: All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \le 1$ ns, pulse repetition rate (PRR) = 0.5 Mpps, pulse width = 5000 ± 10 ns. C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

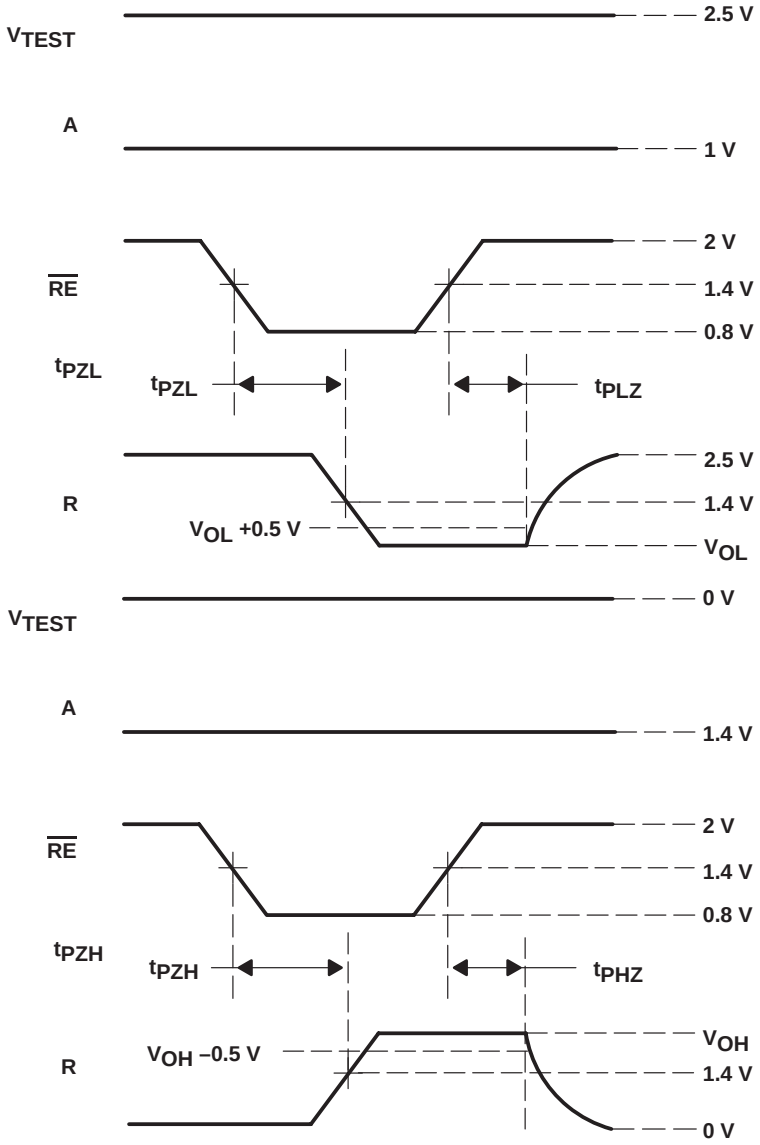


Figure 8. Enable/Disable Time Test Circuit and Waveforms

TYPICAL CHARACTERISTICS

DRIVER
LOW-LEVEL OUTPUT VOLTAGE
vs
LOW-LEVEL OUTPUT CURRENT

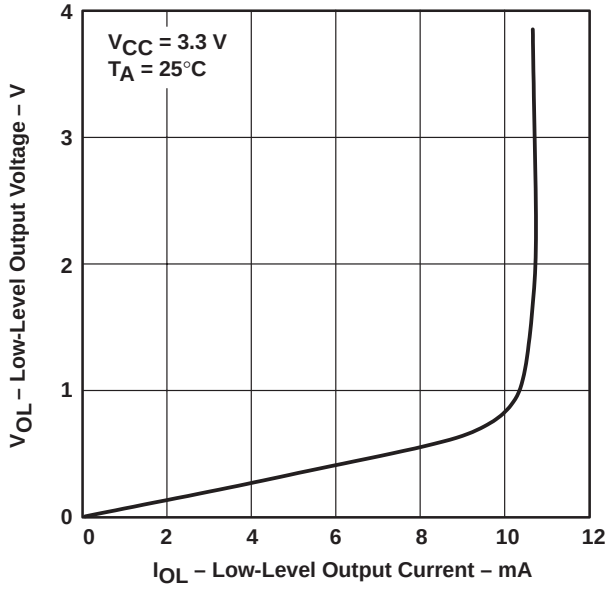


Figure 9

DRIVER
HIGH-LEVEL OUTPUT VOLTAGE
vs
HIGH-LEVEL OUTPUT CURRENT

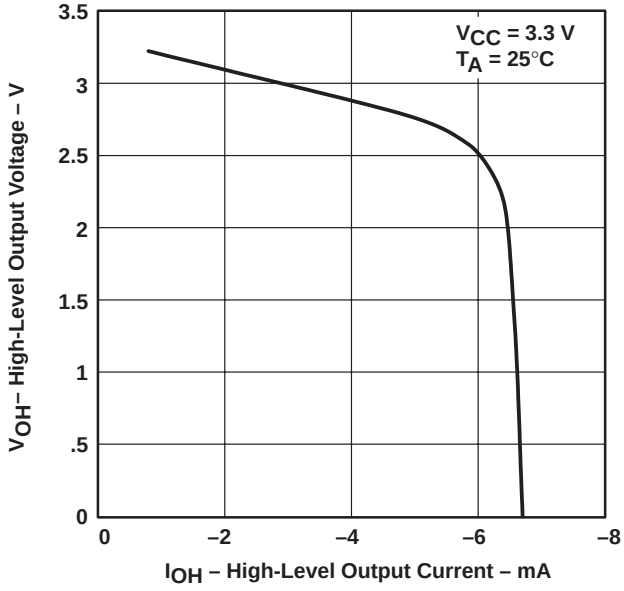


Figure 10

RECEIVER
HIGH-LEVEL OUTPUT VOLTAGE
vs
HIGH-LEVEL OUTPUT CURRENT

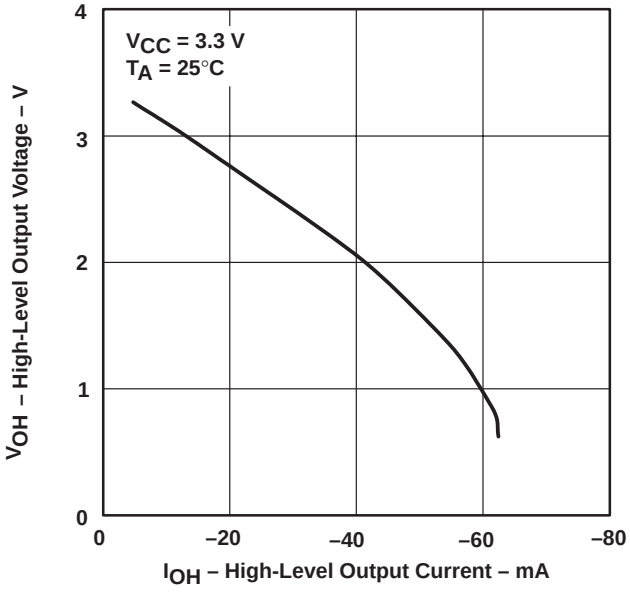


Figure 11

RECEIVER
LOW-LEVEL OUTPUT VOLTAGE
vs
LOW-LEVEL OUTPUT CURRENT

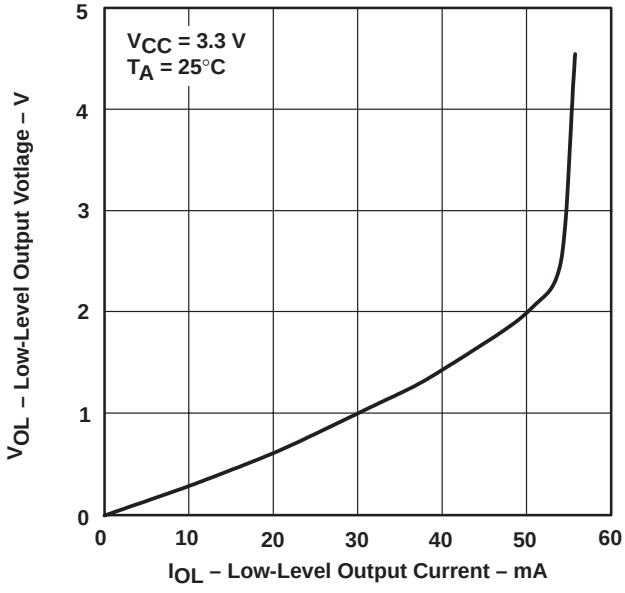


Figure 12

TYPICAL CHARACTERISTICS

DRIVER
HIGH-TO-LOW LEVEL PROPAGATION DELAY TIME
vs
FREE-AIR TEMPERATURE

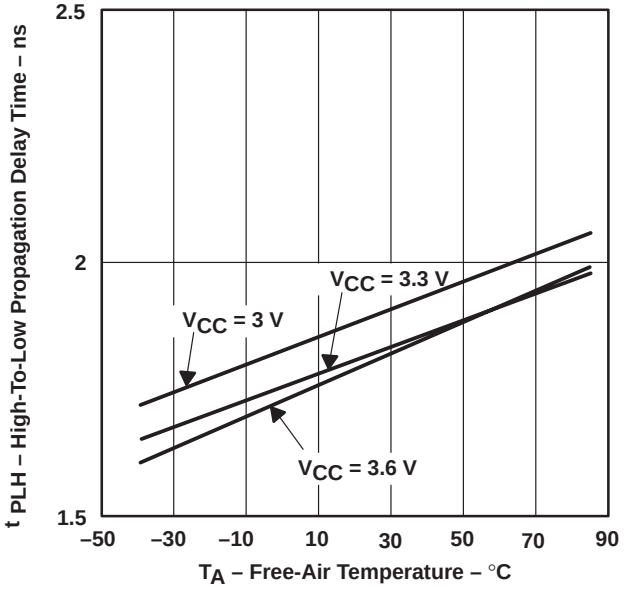


Figure 13

DRIVER
LOW-TO-HIGH LEVEL PROPAGATION DELAY TIME
vs
FREE-AIR TEMPERATURE

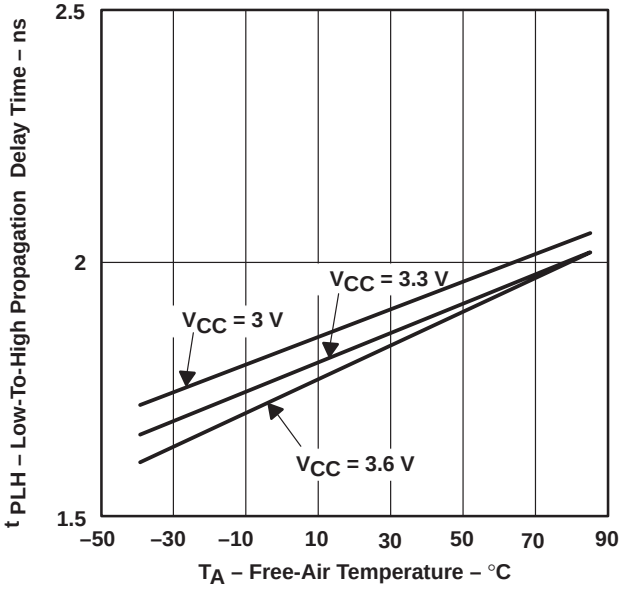


Figure 14

RECEIVER
HIGH-TO-LOW LEVEL PROPAGATION DELAY TIME
vs
FREE-AIR TEMPERATURE

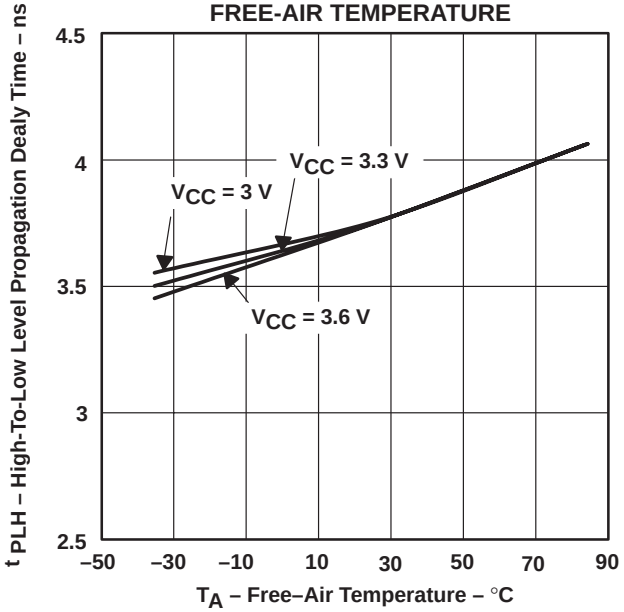


Figure 15

RECEIVER
LOW-TO-HIGH LEVEL PROPAGATION DELAY TIME
vs
FREE–AIR TEMPERATURE

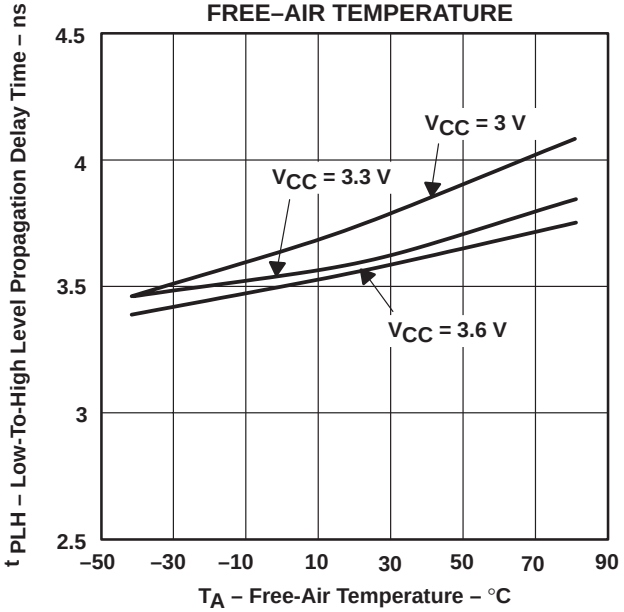


Figure 16

APPLICATION INFORMATION

The devices are generally used as building blocks for high-speed point-to-point data transmission. Ground differences are less than 1 V with a low common-mode output and balanced interface for very low noise emissions. Devices can interoperate with RS-422, PECL, and IEEE-P1596. Drivers/receivers maintain ECL speeds without the power and dual supply requirements.

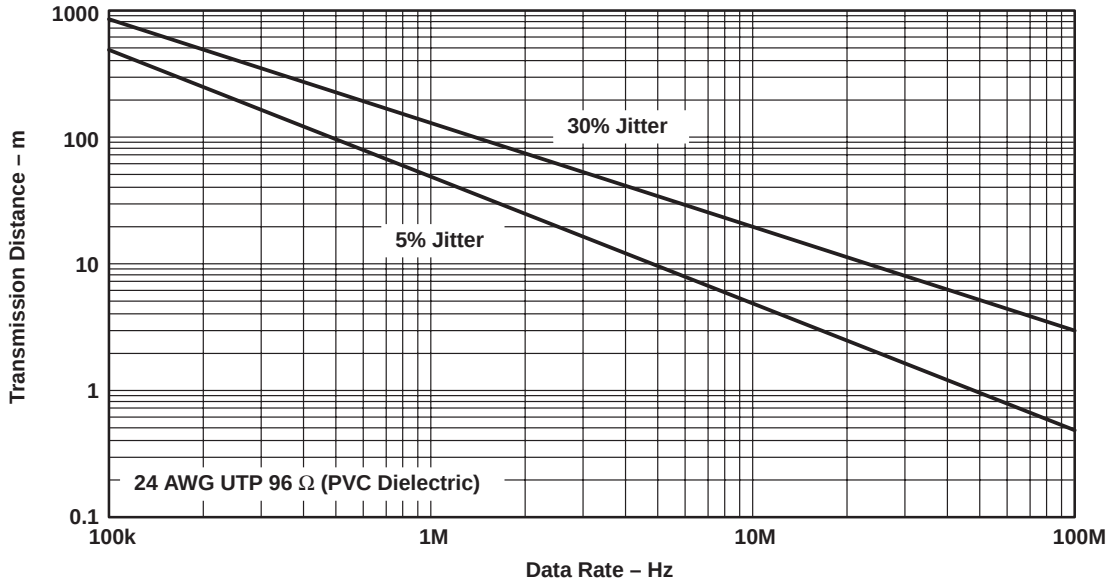


Figure 17. Data Transmission Distance Versus Rate

APPLICATION INFORMATION

fail safe

One of the most common problems with differential signaling applications is how the system responds when no differential voltage is present on the signal pair. The LVDS receiver is like most differential line receivers, in that its output logic state can be indeterminate when the differential input voltage is between –50 mV and 50 mV and within its recommended input common-mode voltage range. TI's LVDS receiver is different in how it handles the open-input circuit situation, however.

Open-circuit means that there is little or no input current to the receiver from the data line itself. This could be when the driver is in a high-impedance state or the cable is disconnected. When this occurs, the LVDS receiver will pull each line of the signal pair to near V_{CC} through 300-kΩ resistors as shown in Figure 18. The fail-safe feature uses an AND gate with input voltage thresholds at about 2.3 V to detect this condition and force the output to a high-level regardless of the differential input voltage.

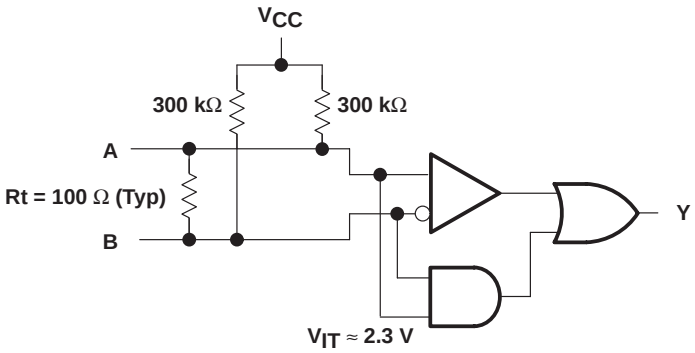
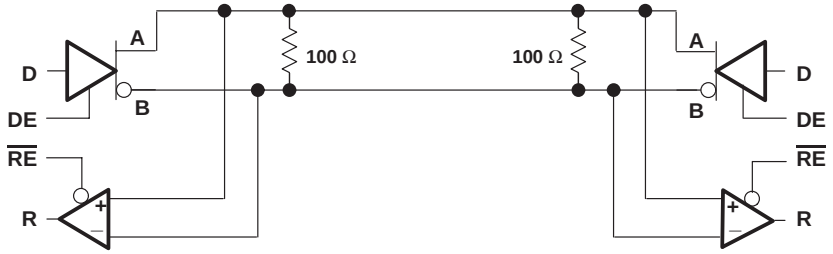


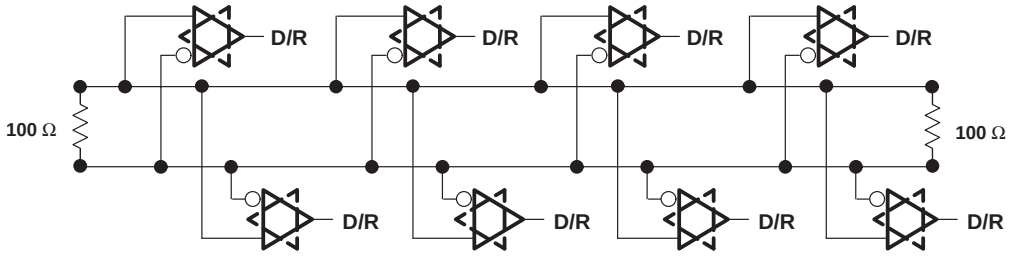
Figure 18. Open-Circuit Fail Safe of the LVDS Receiver

It is only under these conditions that the output of the receiver will be valid with less than a 50-mV differential input voltage magnitude. The presence of the termination resistor, Rt, does not affect the fail-safe function as long as it is connected as shown in the figure. Other termination circuits may allow a dc current to ground that could defeat the pullup currents from the receiver and the fail-safe feature.

APPLICATIONS INFORMATION



Bidirectional Half-Duplex Applications



Multipoint Bus Applications

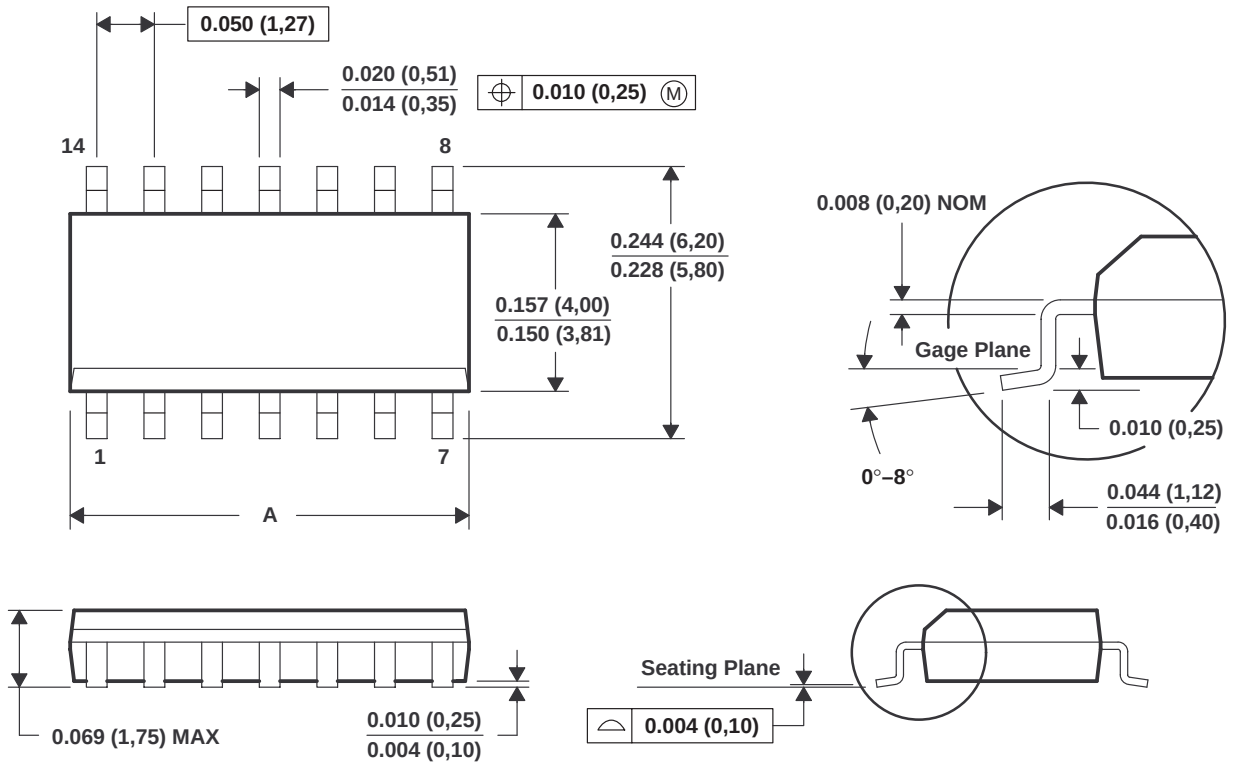
Note A: Keep drivers and receivers as close to the LVDS bus side connector as possible.

Figure 19. Bidirectional Half-Duplex and Multipoint Bus Applications

MECHANICAL DATA

D (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14 PIN SHOWN



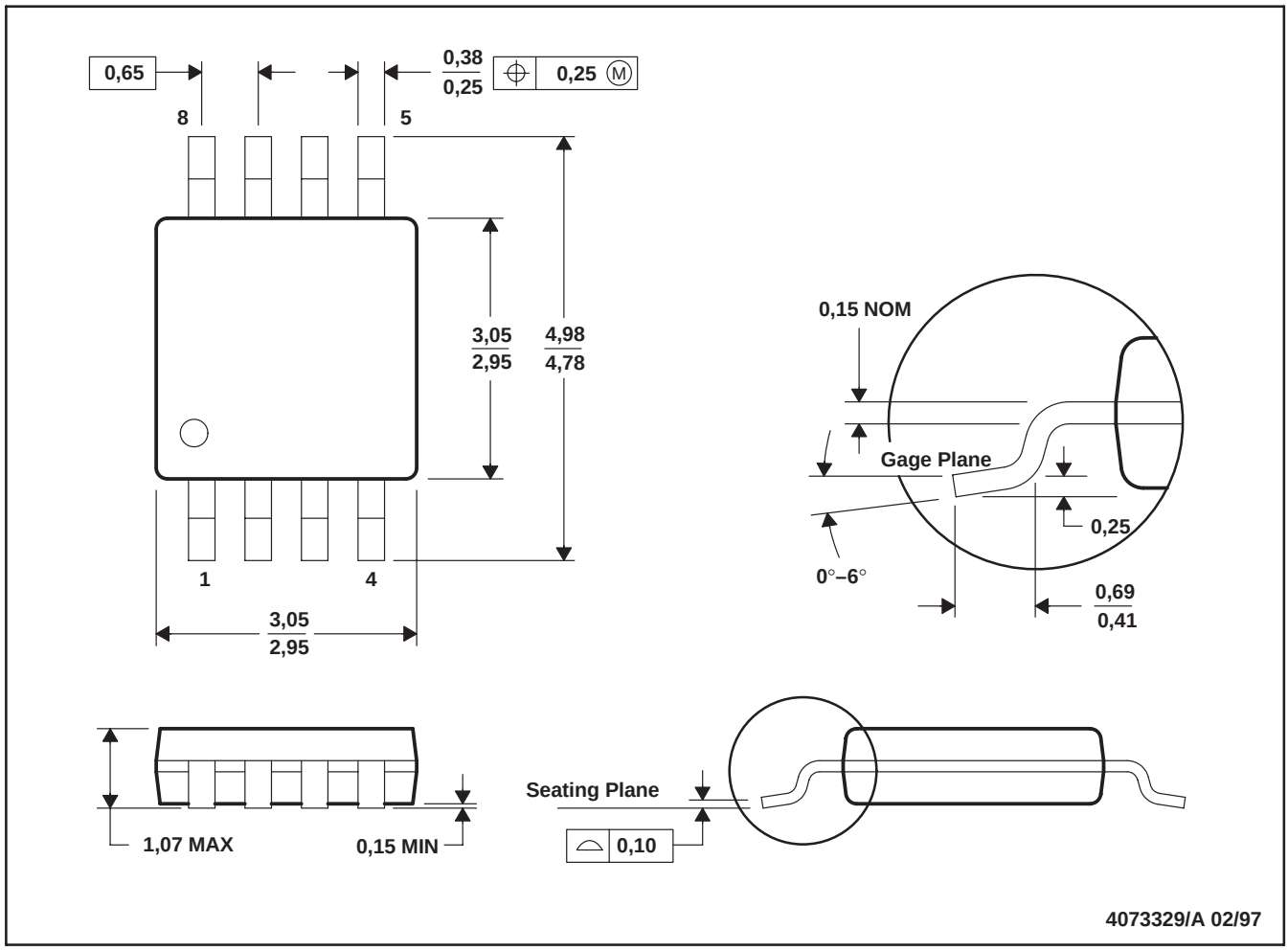
DIM \ PINS **	8	14	16
A MAX	0.197 (5,00)	0.344 (8,75)	0.394 (10,00)
A MIN	0.189 (4,80)	0.337 (8,55)	0.386 (9,80)

4040047/D 10/96

NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).
D. Falls within JEDEC MS-012

MECHANICAL DATA

DGK (R-PDSO-G8) **PLASTIC SMALL-OUTLINE PACKAGE**



NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion.
D. Falls within JEDEC MO-187

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
SN65LVDM176D	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1YEAR/ Level-1-220C-UNLIM
SN65LVDM176DGK	ACTIVE	MSOP	DGK	8	80	None	CU NIPDAU	Level-1-220C-UNLIM
SN65LVDM176DGKR	ACTIVE	MSOP	DGK	8	2500	None	CU NIPDAU	Level-1-220C-UNLIM
SN65LVDM176DR	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1YEAR/ Level-1-220C-UNLIM

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
None: Not yet available Lead (Pb-Free).
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

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